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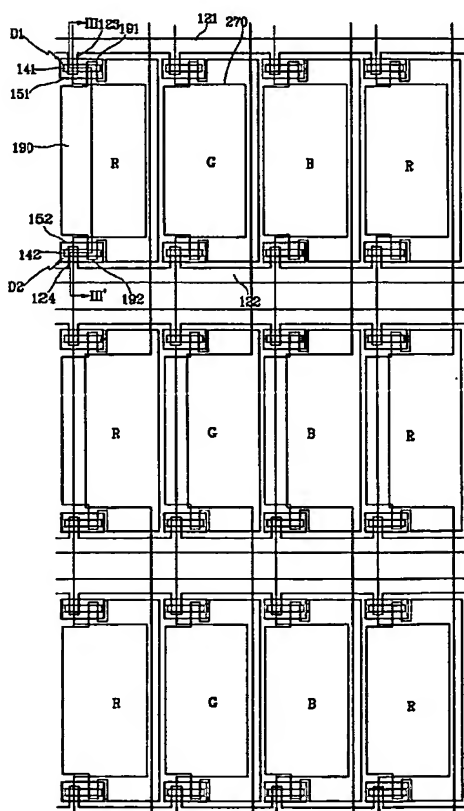
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(54) Title: **LIQUID CRYSTAL DISPLAY OF USING DUAL SELECT DIODE**



(57) Abstract: A liquid crystal display comprising: a first insulating sub-
strate; first and second gate lines (121,122) formed on the first insulating
substrate; a pixel electrode (190) formed on the first insulating substrate;
a first MIM diode (D1) formed on the first insulating substrate connecting
the first gate line (121) and the pixel electrode (190); a second MIM diode
(D2) formed on the first insulating substrate connecting the second gate
line (122) and the pixel electrode (190); a second insulating substrate (210)
facing the first insulating substrate; and a data electrode line (270) formed
on the second insulating substrate and intersecting the first and second gate
lines (121,122), and wherein the data electrode line (270) includes protru-
sions toward right and left sides by turns to overlap a predetermined number
of pixel electrodes (190) of the right and left sides by turns is provided.



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